NCP1200A

Product Preview
PWM Current-Mode Controller for Universal Off-Line Supplies Featuring Low Standby Power

Housed in SO–8 or DIP8 package, the NCP1200A enhances the previous NCP1200 series by offering a reduced optocoupler current together with an increased drive capability. Thanks to its novel concept, the circuit allows the implementation of complete off–line AC/DC adapters, battery charger or a SMPS where standby power is a key parameter.

With an internal structure operating at a fixed 40 kHz, 60 kHz or 100 kHz, the controller supplies itself from the high–voltage rail, avoiding the need of an auxiliary winding. This feature naturally eases the designer task in battery charger applications. Finally, current–mode control provides an excellent audio–susceptibility and inherent pulse–by–pulse control.

When the current setpoint falls below a given value, e.g. the output power demand diminishes, the IC automatically enters the so–called skip cycle mode and provides excellent efficiency at light loads. Because this occurs at a user adjustable low peak current, no acoustic noise takes place.

The NCP1200A features an efficient protective circuitry which, in presence of an overcurrent condition, disables the output pulses while the device enters a safe burst mode, trying to re–start. Once the default has gone, the device auto–recovers.

Features
- No Auxiliary Winding Operation
- Auto–Recovery Internal Output Short–Circuit Protection
- Extremely Low No–Load Standby Power
- Current–Mode Control with Skip–Cycle Capability
- Internal Temperature Shutdown
- Internal Leading Edge Blanking
- 250 mA Peak Current Capability
- Internally Fixed Frequency at 40 kHz, 60 kHz and 100 kHz
- Direct Optocoupler Connection
- SPICE Models Available for TRANsient and AC Analysis
- Pin to Pin Compatible with NCP1200

Typical Applications
- AC/DC Adapters for Portable Devices
- Offline Battery Chargers
- Auxiliary Power Supplies (USB, Appliances, TVs, etc.)

ON Semiconductor™
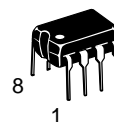
http://onsemi.com

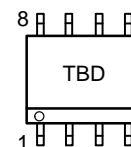### MINIATURE PWM CONTROLLER FOR HIGH POWER AC/DC WALL ADAPTERS AND OFFLINE BATTERY CHARGERS

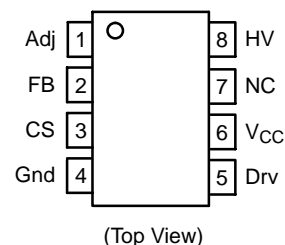### MARKING DIAGRAMS

SO–8
D1, D2 SUFFIX
CASE 751

8
TBD
1

PDIP–8
N SUFFIX
CASE 626

8
TBD
1
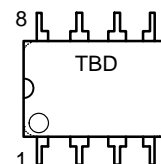
xx	= Specific Device Code
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week

PIN CONNECTIONS

Adj	1	8	HV
FB	2	7	NC
CS	3	6	V$_{CC}$
Gnd	4	5	Drv

(Top View)

ORDERING INFORMATION

Device	Package	Shipping
TBD	TBD	TBD

NCP1200A
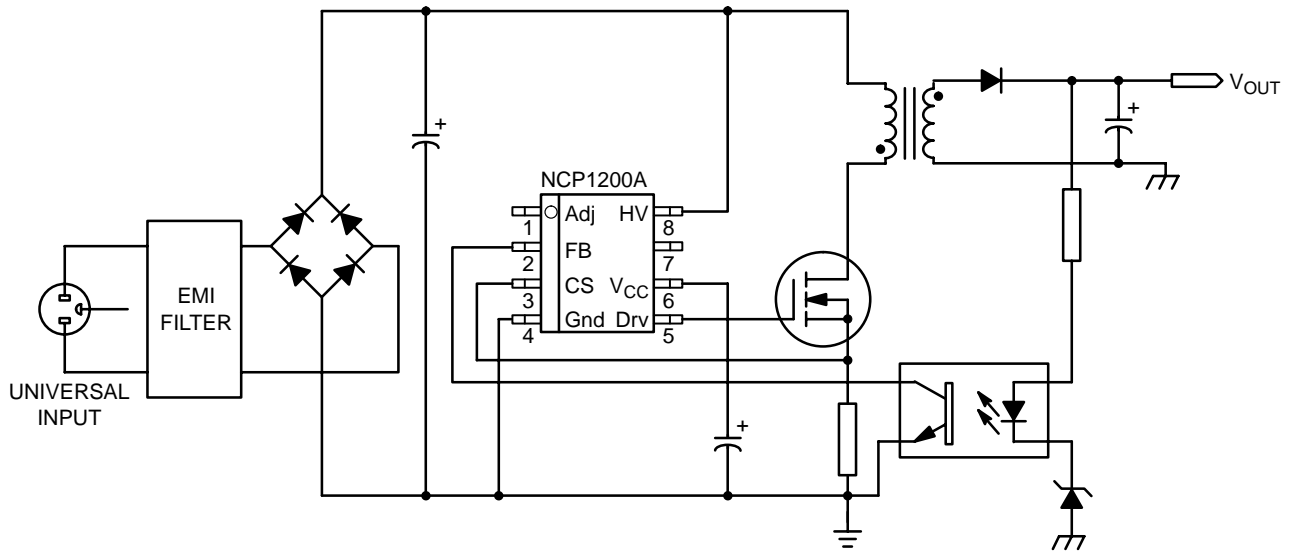
Figure 1. Typical Application Example

PIN FUNCTION DESCRIPTION

| Pin No.	Pin Name	Function	Pin Description
1	Adj	Adjust the skipping peak current	This pin lets you adjust the level at which the cycle skipping process takes place. Shorting this pin to ground, permanently disables the skip cycle feature.
2	FB	Sets the peak current setpoint	By connecting an optocoupler to this pin, the peak current setpoint is adjusted accordingly to the output power demand.
3	CS	Current sense input	This pin senses the primary current and routes it to the internal comparator via an L.E.B.
4	Gnd	The IC ground	–
5	Drv	Driving pulses	The driver's output to an external MOSFET.
6	V_{CC}	Supplies the IC	This pin is connected to an external bulk capacitor of typically 10 μF.
7	NC	–	This unconnected pin ensures adequate creepage distance.
8	HV	Generates the V_{CC} from the line	Connected to the high–voltage rail, this pin injects a constant current into the V_{CC} bulk capacitor.

NCP1200A
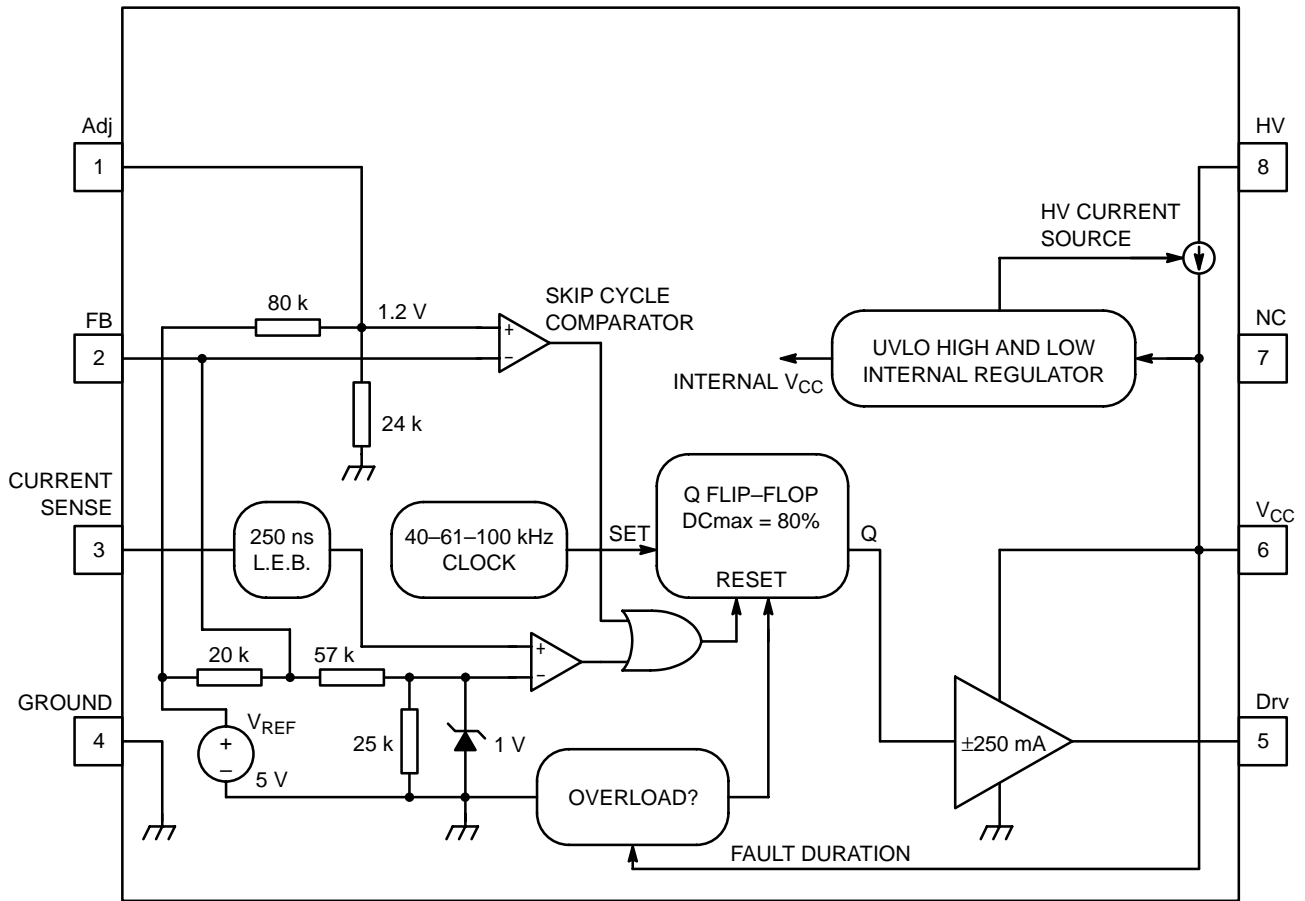
Figure 2. Internal Circuit Architecture

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}	16	V
Thermal Resistance Junction–to–Air, PDIP8 Version Thermal Resistance Junction–to–Air, SOIC Version	$R_{\theta JA}$ $R_{\theta JA}$	100 178	°C/W °C/W
Maximum Junction Temperature	$T_{J(max)}$	150	°C
Temperature Shutdown	–	140	°C
Storage Temperature Range	–	−60 to +150	°C
ESD Capability, HBM Model (All pins except V_{CC} and HV)	–	2.0	kV
ESD Capability, Machine Model	–	200	V
Maximum Voltage on Pin 8 (HV), Pin 6 (V_{CC}) Grounded	–	450	V
Maximum Voltage on Pin 8 (HV), Pin 6 (V_{CC}) Decoupled to Ground with 10 μF	–	500	V

ELECTRICAL CHARACTERISTICS (For typical values $T_J = 25°C$, for min/max values $T_J = 0°C$ to $+125°C$, Max $T_J = 150°C$, $V_{CC} = 11$ V unless otherwise noted.)

Characteristic	Symbol	Pin	Min	Typ	Max	Unit
Dynamic Self–Supply (All frequency versions, otherwise noted)						
V_{CC} Increasing Level at which the Current Source Turns–Off	$V_{CC(off)}$	6	11.2	12.1	13.1	V
V_{CC} Decreasing Level at which the Current Source Turns–On	$V_{CC(on)}$	6	9.0	10	11	V
V_{CC} Decreasing Level at which the Latch–off Phase Ends	$V_{CC(latch)}$	6	–	5.4	–	V
Internal IC Consumption, No Output Load on Pin 6	ICC1	6	–	700	930 (Note 1)	μA
Internal IC Consumption, 1.0 nF Output Load on Pin 6, $F_{SW} = 40$ kHz	ICC2	6	–	1.2	1.4 (Note 2)	mA
Internal IC Consumption, 1.0 nF Output Load on Pin 6, $F_{SW} = 60$ kHz	ICC2	6	–	1.3	1.9 (Note 2)	mA
Internal IC Consumption, 1.0 nF Output Load on Pin 6, $F_{SW} = 100$ kHz	ICC2	6	–	2.2	2.7 (Note 2)	mA
Internal IC Consumption, Latch–off Phase	ICC3	6	–	340	–	μA
Internal Start–Up Current Source ($T_J > 0°C$)						
High–Voltage Current Source, $V_{CC} = 10$ V	IC1	8	4.0	7.0	–	mA
High–Voltage Current Source, $V_{CC} = 0$	IC2	8	–	13	–	mA
Drive Output						
Output Voltage Rise–Time @ CL = 1.0 nF, 10–90% of Output Signal	T_r	5	–	67	–	ns
Output Voltage Fall–Time @ CL = 1.0 nF, 10–90% of Output Signal	T_f	5	–	25	–	ns
Source Resistance	R_{OH}	5	27	41	61	Ω
Sink Resistance	R_{OL}	5	5.0	10	21	Ω
Current Comparator (Pin 5 unloaded)						
Input Bias Current @ 1.0 V Input Level on Pin 3	I_{IB}	3	–	0.02	–	μA
Maximum Internal Current Setpoint	I_{Limit}	3	0.8	0.9	1.0	V
Default Internal Current Setpoint for Skip Cycle Operation	I_{Lskip}	3	–	360	–	mV
Propagation Delay from Current Detection to Gate OFF State	T_{DEL}	3	–	90	160	ns
Leading Edge Blanking Duration	T_{LEB}	3	–	230	–	ns
Internal Oscillator ($V_{CC} = 11$ V, pin 5 loaded by 1.0 kΩ)						
Oscillation Frequency, 40 kHz Version	f_{OSC}	–	36	42	48	kHz
Built–in Frequency Jittering, $f_{sw} = 40$ kHz	f_{jitter}	–	–	±	–	kHz
Oscillation Frequency, 60 kHz Version	f_{OSC}	–	52	61	70	kHz
Built–in Frequency Jittering, $f_{sw} = 60$ kHz	f_{jitter}	–	–	±	–	kHz
Oscillation Frequency, 100 kHz Version	f_{OSC}	–	86	103	116	kHz
Built–in Frequency Jittering, $f_{sw} = 100$ kHz	f_{jitter}	–	–	±	–	kHz
Maximum Duty–Cycle	Dmax	–	74	80	87	%
Feedback Section ($V_{CC} = 11$ V, pin 5 loaded by 1.0 kΩ)						
Internal Pull–up Resistor	R_{up}	2	–	20	–	kΩ
Pin 3 to Current Setpoint Division Ratio	I_{ratio}	–	–	3.3	–	–
Skip Cycle Generation						
Default Skip Mode Level	V_{skip}	1	0.95	1.1	1.45	V
Pin 1 Internal Output Impedance	Z_{out}	1	–	22	–	kΩ

1. Max value at $T_J = 0°C$.
2. Maximum value @ $T_J = 25°C$, please see characterization curves.

NCP1200A

APPLICATION INFORMATION

Introduction

The NCP1200A implements a standard current mode architecture where the switch–off time is dictated by the peak current setpoint. This component represents the ideal candidate where low part–count is the key parameter, particularly in low–cost AC/DC adapters, auxiliary supplies, etc. Thanks to its high–performance High–Voltage technology, the NCP1200A incorporates all the necessary components normally needed in UC384X based supplies: timing components, feedback devices, low–pass filter and self–supply. This later point emphasizes the fact that ON Semiconductor's NCP1200A does NOT need an auxiliary winding to operate: the product is naturally supplied from the high–voltage rail and delivers a V_{CC} to the IC. This system is called the Dynamic Self–Supply (DSS).

Dynamic Self–Supply

The DSS principle is based on the charge/discharge of the V_{CC} bulk capacitor from a low level up to a higher level. We can easily describe the current source operation with a bunch of simple logical equations:

POWER–ON: IF V_{CC} < VCC$_H$ THEN Current Source is ON, no output pulses

IF V_{CC} decreasing > VCC$_L$ THEN Current Source is OFF, output is pulsing

IF V_{CC} increasing < VCC$_H$ THEN Current Source is ON, output is pulsing

Typical values are: VCC$_H$ = 12 V, VCC$_L$ = 10 V

To better understand the operational principle, **Figure 3**'s sketch offers the necessary light:

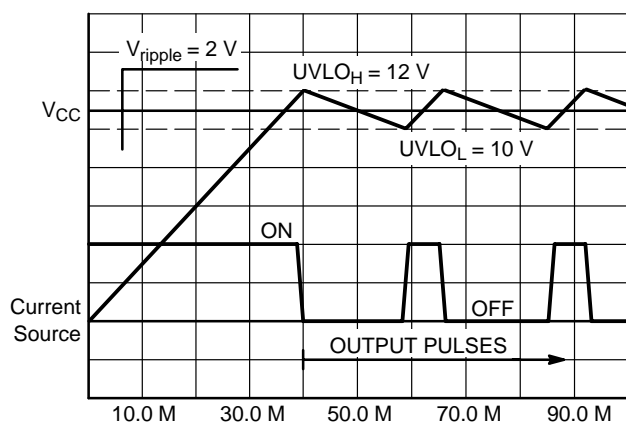**Figure 3. The charge/discharge cycle over a 10 μF V$_{CC}$ capacitor**

The DSS behavior actually depends on the internal IC consumption and the MOSFET's gate charge Qg. If we select a MOSFET like the MTP2N60E, Qg max equals 22 nC. With a maximum switching frequency of 70 kHz for the P60 version, the average power necessary to drive the MOSFET (excluding the driver efficiency and neglecting various voltage drops) is:

$F_{SW} \cdot Qg \cdot V_{CC}$ with

F_{SW} = maximum switching frequency

Qg = MOSFET's gate charge

V_{CC} = V_{GS} level applied to the gate

To obtain the final IC current, simply divide this result by V_{CC}: $I_{driver} = F_{SW} \cdot Qg = 1.54$ mA. The total standby power consumption at no–load will therefore heavily rely on the internal IC consumption plus the above driving current (altered by the driver's efficiency). Suppose that the IC is supplied from a 350 VDC line. The current flowing through pin 8 is a direct image of the NCP1200A consumption (neglecting the switching losses of the HV current source). If ICC2 equals 2.3 mA @ T$_J$ = 25°C, then the power dissipated (lost) by the IC is simply: 350 x 2.3 m = 805 mW. For design and reliability reasons, it would be interesting to reduce this source of wasted power which increases the die temperature. This can be achieved by using different methods:

1. Use a MOSFET with lower gate charge Qg
2. Connect pin through a diode (1N4007 typically) to one of the mains input. The average value on pin 8 becomes $\frac{V_{MAINS(peak)} \cdot 2}{\pi}$. Our power contribution example drops to: 223 x 2.3 m = 512 mW. If a resistor is installed between the mains and the diode, you further force the dissipation to migrate from the package to the resistor. The resistor value should account for low–line startups.
3. Permanently force the V_{CC} level above VCC$_H$ with an auxiliary winding. It will automatically disconnect the internal start–up source and the IC will be fully self–supplied from this winding. Again, the total power drawn from the mains will significantly decrease. Make sure the auxiliary voltage never exceeds the 16 V limit.
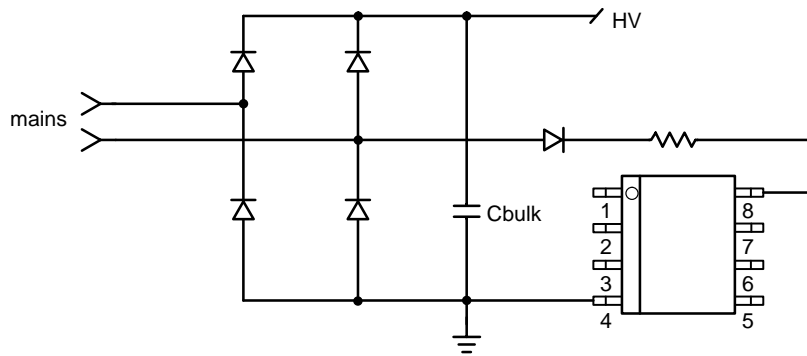
NCP1200A

Figure 4.

A simple diode naturally reduces the average voltage on pin 8

Skipping Cycle Mode

The NCP1200A automatically skips switching cycles when the output power demand drops below a given level. This is accomplished by monitoring the FB pin. In normal operation, pin 2 imposes a peak current accordingly to the load value. If the load demand decreases, the internal loop asks for less peak current. When this setpoint reaches a determined level, the IC prevents the current from decreasing further down and starts to blank the output pulses: the IC enters the so–called skip cycle mode, also named controlled burst operation. The power transfer now depends upon the width of the pulse bunches (**Figure 6**). Suppose we have the following component values:

Lp, primary inductance = 1 mH
F_{SW}, switching frequency = 61 kHz
Ip skip = 200 mA (or 333 mV/R_{SENSE})

The theoretical power transfer is therefore:

$$\frac{1}{2} \cdot Lp \cdot Ip^2 \cdot F_{SW} = 1.2 \text{ W}$$

If this IC enters skip cycle mode with a bunch length of 20 ms over a recurrent period of 100 ms, then the total power transfer is: 1.2 **.** 0.2 = 240 mW.

To better understand how this skip cycle mode takes place, a look at the operation mode versus the FB level immediately gives the necessary insight:
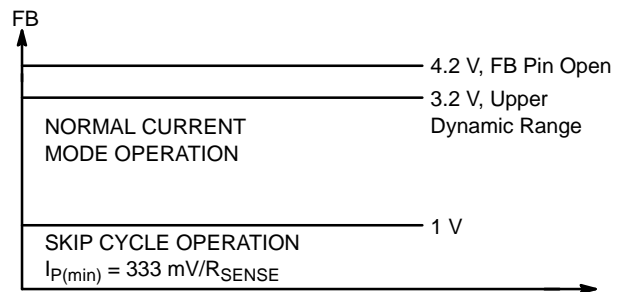
Figure 5.

When FB is above the skip cycle threshold (1 V by default), the peak current cannot exceed 1 V/R_{SENSE}. When the IC enters the skip cycle mode, the peak current cannot go below Vpin1 / 3.3. The user still has the flexibility to alter this 1 V by either shunting pin 1 to ground through a resistor or raising it through a resistor up to the desired level. Grounding pin 1 permanently invalidates the skip cycle operation.
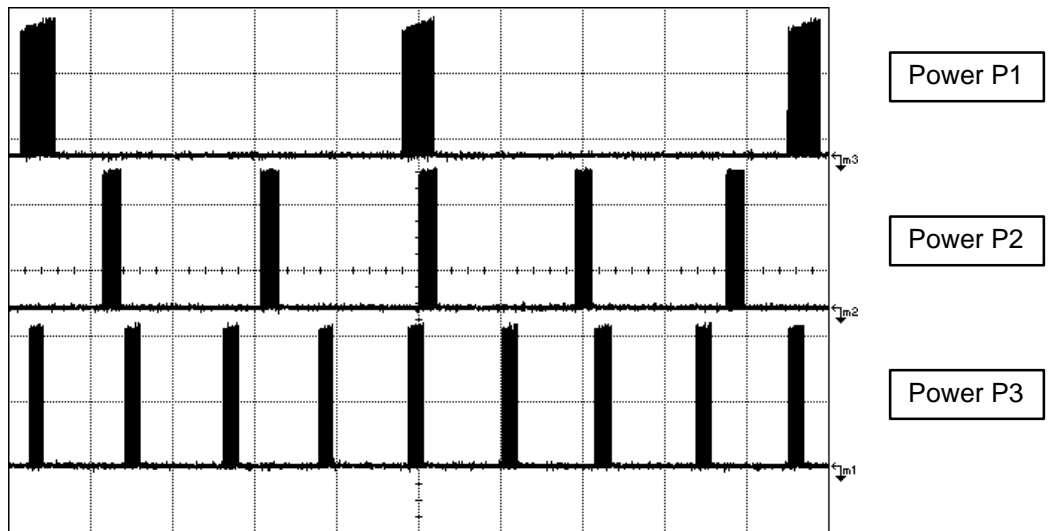
Figure 6.

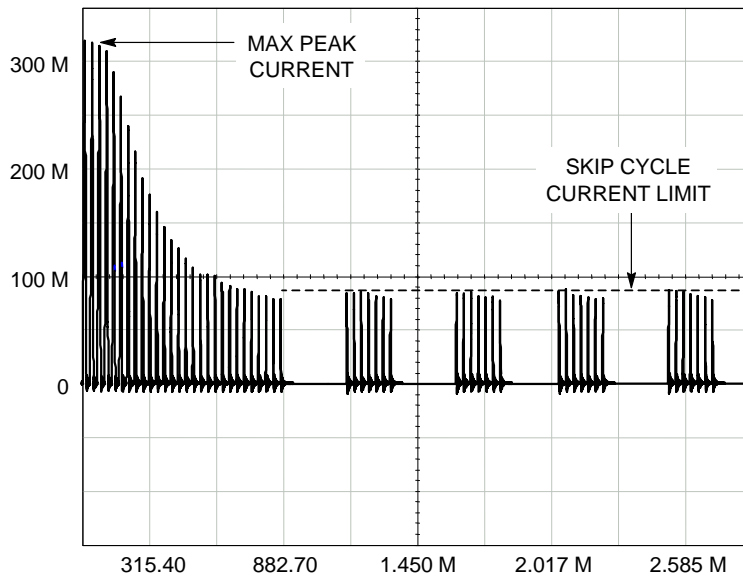Output Pulses at Various Power Levels (X = 5.0 μs/div) P1 < P2 < P3

Figure 7.

The Skip Cycle Takes Place at Low Peak Currents which Guaranties Noise–Free Operation

We recommend a pin1 operation between 400 mV and 1.3 V that will fix the skip peak current level between 120 mV / R_{SENSE} and 390 mV / R_{SENSE}.

Non–latching shutdown

In some cases, it might be desirable to shut off the part temporarily and authorize its re–start once the default has disappeared. This option can easily be accomplished through a single NPN bipolar transistor wired between FB and ground. By pulling FB below the Adj pin 1 level, the output pulses are disabled as long as FB is pulled below pin 1. As soon as FB is relaxed, the IC resumes its operation. **Figure 8** depicts the application example:

NCP1200A
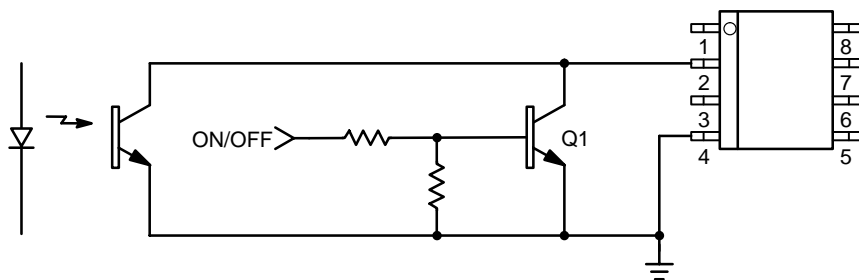
Figure 8.

Another Way of Shutting Down the IC without a Definitive Latch–Off State

Power dissipation

The NCP1200A is directly supplied from the DC rail through the internal DSS circuitry. The average current flowing through the DSS is therefore the direct image of the NCP1200A current consumption. The total power dissipation can be evaluated using: $(V_{HVDC} - 11\text{ V}) \cdot ICC2$. If we operate the device on a 250 VAC rail, the maximum rectified voltage can go up to 350 VDC. However, as the characterization curves show, the current consumption drops at high junction temperature, which quickly occurs thanks to the DSS operation. At $T_J = 50°C$, $ICC2 = 1.7$ mA for the 61 kHz version over a 1 nF capacitive load. As a result, the NCP1200A will dissipate 350 . 1.7 mA@T_J = 50°C = 595 mW. The SO–8 package offers a junction–to–ambient thermal resistance $R_{\theta JA}$ of 178°C/W. Adding some copper area around the PCB footprint will help decreasing this number: 12 mm x 12 mm to drop $R_{\theta JA}$ down to 100°C/W with 35 μ copper thickness (1 oz.) or 6.5 mm x 6.5 mm with 70 μ copper thickness (2 oz.). With this later number, we can compute the maximum power dissipation the package accepts at an ambient of 50°C:

$$Pmax = \frac{T_{Jmax} - T_{Amax}}{R_{\theta JA}} = 750\text{ mW}$$

which is okay with our previous budget. For the DIP8 package, adding a min–pad area of 80 mm^2 of 35 μ copper (1 oz.), $R_{\theta JA}$ drops from 100°C/W to about 75°C/W.

In the above calculations, ICC2 is based on a 1 nF output capacitor. As seen before, ICC2 will depend on your MOSFET's Qg: $ICC2 \approx ICC1 + F_{SW} \times Qg$. Final calculation shall thus accounts for the total gate–charge Qg your MOSFET will exhibit. The same methodology can be applied for the 100 kHz version but care must be taken to keep T_J below the 125°C limit with the D100 (SOIC) version and activated DSS in high–line conditions.

If the power estimation is beyond the limit, other solutions are possible a) add a series diode with pin 8 (as suggested in the above lines) and connect it to the half rectified wave. As a result, it will drop the average input voltage and lower the dissipation to: $\frac{350 \cdot 2}{\pi} \cdot 1.7\text{ m} = 380\text{ mW}$ b) put an auxiliary winding to disable the DSS and decrease the power consumption to $V_{CC} \times ICC2$. The auxiliary level should be thus that the rectified auxiliary voltage permanently stays above 10 V (to not re–activate the DSS) and is safely kept below the 16 V maximum rating.

Overload operation

In applications where the output current is purposely not controlled (e.g. wall adapters delivering raw DC level), it is interesting to implement a true short–circuit protection. A short–circuit actually forces the output voltage to be at a low level, preventing a bias current to circulate in the optocoupler LED. As a result, the FB pin level is pulled up to 4.2 V, as internally imposed by the IC. The peak current setpoint goes to the maximum and the supply delivers a rather high power with all the associated effects. Please note that this can also happen in case of feedback loss, e.g. a broken optocoupler. To account for this situation, NCP1200A hosts a dedicated overload detection circuitry. Once activated, this circuitry imposes to deliver pulses in a burst manner with a low duty–cycle. The system auto–recovers when the fault condition disappears.

During the start–up phase, the peak current is pushed to the maximum until the output voltage reaches its target and the feedback loop takes over. This period of time depends on normal output load conditions and the maximum peak current allowed by the system. The time–out used by this IC works with the V_{CC} decoupling capacitor: as soon as the V_{CC} decreases from the UVLO$_H$ level (typically 12 V) the device internally watches for an overload current situation. If this condition is still present when the UVLO$_L$ level is reached, the controller stops the driving pulses, prevents the self–supply current source to restart and puts all the circuitry in standby, consuming as little as 350 μA typical (ICC3 parameter). As a result, the V_{CC} level slowly discharges toward 0.
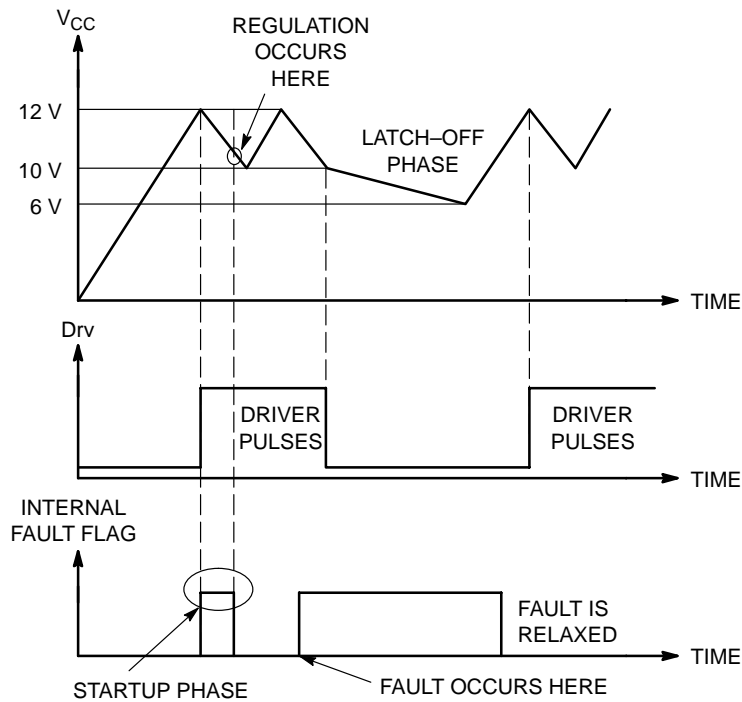
Figure 9.

If the fault is relaxed during the V_{CC} natural fall down sequence, the IC automatically resumes.
If the fault still persists when V_{CC} reached $UVLO_L$, then the controller cuts everything off until recovery.

When this level crosses 6 V typical, the controller enters a new startup phase by turning the current source on: V_{CC} rises toward 12 V and again delivers output pulses at the $UVLO_H$ crossing point. If the fault condition has been removed before $UVLO_L$ approaches, then the IC continues its normal operation. Otherwise, a new fault cycle takes place. **Figure 9** shows the evolution of the signals in presence of a fault.

Calculating the V_{CC} capacitor

As the above section describes, the fall down sequence depends upon the V_{CC} level: how long does it take for the V_{CC} line to go from 12 V to 10 V? The required time depends on the start–up sequence of your system, i.e. when you first apply the power to the IC. The corresponding transient fault duration due to the output capacitor charging must be less than the time needed to discharge from 12 V to 10 V, otherwise the supply will not properly start. The test consists in either simulating or measuring in the lab how much time the system takes to reach the regulation at full load. Let's suppose that this time corresponds to 6 ms. Therefore a V_{CC} fall time of 10 ms could be well appropriated in order to not trigger the overload detection circuitry. If the corresponding IC consumption, including the MOSFET drive, establishes at 1.8 mA for instance, we can calculate the required capacitor using the following formula: $\Delta t = \dfrac{\Delta V \cdot C}{i}$, with $\Delta V = 2$ V. Then for a wanted Δt of 10 ms, C equals 9 μF or 10 μF for a standard value. When an overload condition occurs, the IC blocks its internal circuitry and its consumption drops to 350 μA typical. This happens at $V_{CC} = 10$ V and it remains stuck until V_{CC} reaches 6 V: we are in latch–off phase. Again, using the calculated 10 μF and 350 μA current consumption, this latch–off phase lasts: 109 ms.

NCP1200A

## PACKAGE DIMENSIONS

PDIP–8
N SUFFIX
CASE 626–05
ISSUE L
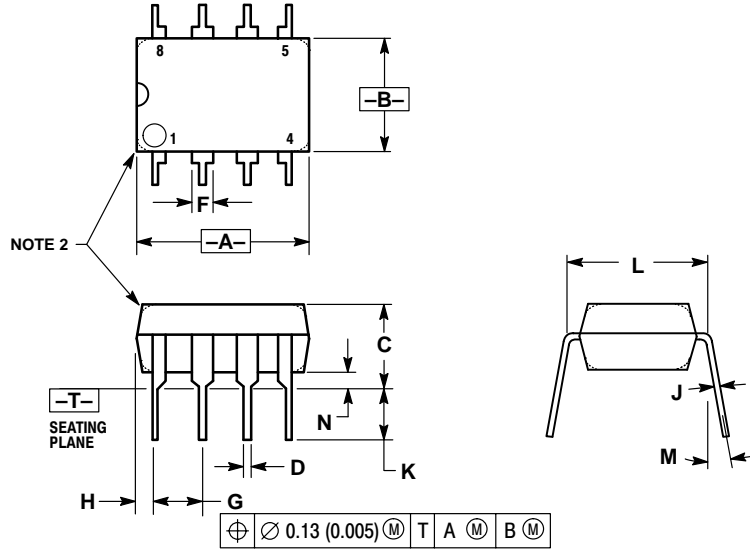
NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

NCP1200A

PACKAGE DIMENSIONS

SO–8
D1, D2 SUFFIX
CASE 751–07
ISSUE W
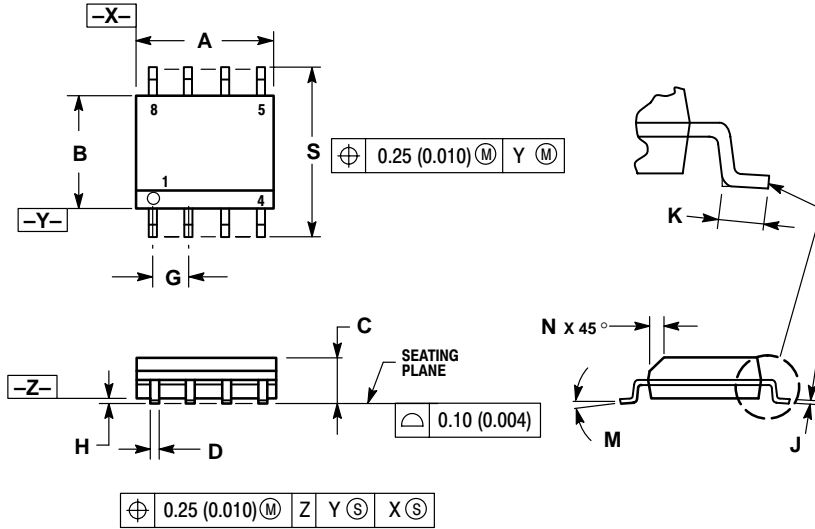
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

NCP1200A